

Is Now Part of



ON Semiconductor®

To learn more about ON Semiconductor, please visit our website at www.onsemi.com

Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild guestions@onsemi.com.

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any EDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officer



LM2904,LM358/LM358A,LM258/ LM258A

Dual Operational Amplifier

Features

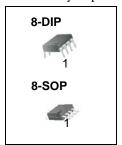
- Internally Frequency Compensated for Unity Gain
- Large DC Voltage Gain: 100dB
- Wide Power Supply Range: LM258/LM258A, LM358/LM358A: 3V~32V (or ±1.5V ~ 16V)

LM2904 : $3V \sim 26V$ (or $\pm 1.5V \sim 13V$)

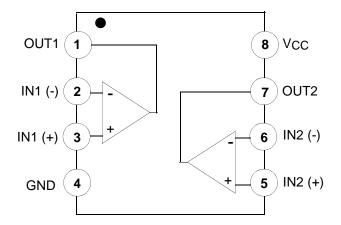
- Input Common Mode Voltage Range Includes Ground
- Large Output Voltage Swing: 0V DC to Vcc -1.5V DC
- Power Drain Suitable for Battery Operation.

Description

The LM2904,LM358/LM358A, LM258/LM258A consist of two independent, high gain, internally frequency compensated operational amplifiers which were designed specifically to operate from a single power supply over a wide range of voltage. Operation from split power supplies is also possible and the low power supply current drain is independent of the magnitude of the power supply voltage. Application areas include transducer amplifier, DC gain blocks and all the conventional OP-AMP circuits which now can be easily implemented in single power supply systems.

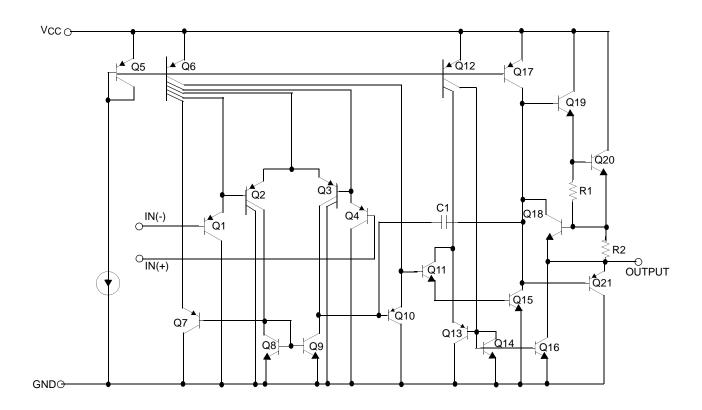


Internal Block Diagram



Schematic Diagram

(One section only)



Absolute Maximum Ratings

Parameter	Symbol	LM258/LM258A	LM358/LM358A	LM2904	Unit
Supply Voltage	Vcc	±16 or 32	±16 or 32	±13 or 26	V
Differential Input Voltage	VI(DIFF)	32	32	26	V
Input Voltage	Vı	-0.3 to +32	-0.3 to +32	-0.3 to +26	V
Output Short Circuit to GND VCC≤15V, TA = 25°C(One Amp)	-	Continuous	Continuous	Continuous	-
Operating Temperature Range	TOPR	-25 ~ +85	0 ~ +70	-40 ~ +85	°C
Maximun Junction Temperature	TJ(MAX)	+150	+150	+150	°C
Storage Temperature Range	TSTG	-65 ~ +150	-65 ~ +150	-65 ~ +150	°C

Electrical Characteristics

(VCC = 5.0V, VEE = GND, $T_A = 25$ °C, unless otherwise specified)

Doromotor	Compleal	Conditions -		LM258			LM358				11		
Parameter	Symbol			Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
Input Offset Voltage	VIO	$VCM = 0V$ $-1.5V$ $VO(P) = 1.4$ $RS = 0\Omega$		-	2.9	5.0	-	2.9	7.0	-	2.9	7.0	mV
Input Offset Current	lio	-		-	3	30	-	5	50	-	5	50	nA
Input Bias Current	IBIAS	-		-	45	150	-	45	250	-	45	250	nA
Input Voltage Range	V _{I(R)}	VCC = 30V (LM2904, V		0	ı	VCC -1.5	0	ı	VCC -1.5	0	-	VCC -1.5	V
Supply Current	ICC	$RL = \infty$, VC (LM2904, V		-	0.8	2.0	-	0.8	2.0	-	0.8	2.0	mA
Зарріу Сапені	100	$R_L = \infty$, V_C	CC = 5V	-	0.5	1.2	-	0.5	1.2	-	0.5	1.2	mA
Large Signal Voltage Gain	G∨	$V_{CC} = 15V$ $R_{L} = 2k\Omega$ $V_{O(P)} = 1V$		50	100	-	25	100	-	25	100	-	V/mV
	VO(H)	Vcc=30V	$R_L = 2k\Omega$	26	-	-	26	-	-	22	-	-	V
Output Voltage Swing		(VCC =26V for LM2904)	RL= 10kΩ	27	28	-	27	28	-	23	24	-	V
	VO(L)	Vcc = 5V,	R _L = 10kΩ	-	5	20	-	5	20		5	20	mV
Common-Mode Rejection Ratio	CMRR	-		70	85	-	65	80	-	50	80	-	dB
Power Supply Rejection Ratio	PSRR	-		65	100	ı	65	100	ı	50	100	-	dB
Channel Separation	cs	f = 1kHz to (Note1)	20kHz	1	120	1	-	120	ı	-	120	-	dB
Short Circuit to GND	Isc	-		ı	40	60	-	40	60	-	40	60	mA
	ISOURCE	VI(+) = 1V, VI(-) = 0V, VCC = 15V, VO(P) = 2V		20	30	-	20	30	-	20	30	-	mA
Output Current		VI(+) = 0V, VI(-) = 1V, VCC = 15V, VO(P) = 2V		10	15	-	10	15	-	10	15	-	mA
	ISINK	$V_{I(+)} = 0V, V_{I(-)} = 1V$, $V_{CC} = 15V$, $V_{O(P)} = 200mV$		12	100	-	12	100	-	-	-	-	μΑ
Differential Input Voltage	VI(DIFF)	-		-	-	Vcc	-	-	Vcc	-	-	Vcc	V

Note:

^{1.} This parameter, although guaranteed, is not 100% tested in production.

Electrical Characteristics (Continued)

(Vcc= 5.0V, VEE = GND, unless otherwise specified)

The following specification apply over the range of -25°C \leq TA \leq +85°C for the LM258; and the 0°C \leq TA \leq +70°C for the LM358; and the -40°C \leq TA \leq +85°C for the LM2904

Danamatan	Council of	Conditions			LM25	8		LM35	8	L	11		
Parameter	Symbol			Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
Input Offset Voltage	VIO	$V_{CM} = 0V$ to V_{CC} -1.5V $V_{O(P)} = 1.4V$, $R_{S} = 0\Omega$		-	-	7.0	-	-	9.0	-	-	10.0	mV
Input Offset Voltage Drift	ΔVΙΟ/ΔΤ	$Rs = 0\Omega$		-	7.0	-	-	7.0	-	-	7.0	-	μV/°C
Input Offset Current	lio	-	-	-	-	100	-	-	150	-	45	200	nA
Input Offset Current Drift	ΔΙΙΟ/ΔΤ	-	-	-	10	-	-	10	-	-	10	-	pA/°C
Input Bias Current	IBIAS	-		-	40	300	-	40	500	-	40	500	nA
Input Voltage Range	VI(R)	VCC = 30V (LM2904 , VCC = 26V)		0	-	VCC -2.0	0	-	VCC -2.0	0	-	VCC -2.0	V
Large Signal Voltage Gain	G∨	$V_{CC} = 15V$, $R_L = 2.0kΩ$ $V_{O(P)} = 1V$ to 11V		25	-	-	15	-	-	15	-	-	V/mV
		Vcc=30V	$R_L = 2k\Omega$	26	-	-	26	-	-	22	-	-	V
Output Voltage Swing	VO(H)	(VCC = 26V for LM2904)	RL=10kΩ	27	28	-	27	28	-	23	24	-	V
	VO(L)	VCC = 5V,	R _L =10kΩ	-	5	20	-	5	20	-	5	20	mV
Output Current	ISOURCE	V _{I(+)} = 1V, V _{I(-)} = 0V, V _{CC} = 15V, V _{O(P)} = 2V		10	30	-	10	30	-	10	30	-	mA
Output Current	ISINK	VI(+) = 0V, VI(-) = 1V, VCC = 15V, VO(P) = 2V		5	8	-	5	9	-	5	9	-	mA
Differential Input Voltage	VI(DIFF)	-	•	-	-	Vcc	-	-	Vcc	-	-	Vcc	V

Electrical Characteristics (Continued)

(VCC = 5.0V, VEE = GND, TA = 25°C, unless otherwise specified)

Danamatan	Comple al	O a m alit		LM258	Α		Unit			
Parameter	Symbol	Condit	ions	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
Input Offset Voltage	VIO	VCM = 0V to V $VO(P) = 1.4V$		-	1.0	3.0	-	2.0	3.0	mV
Input Offset Current	lio	-		-	2	15	-	5	30	nA
Input Bias Current	IBIAS	-		-	40	80	-	45	100	nA
Input Voltage Range	VI(R)	VCC = 30V		0	-	VCC -1.5	0	-	VCC -1.5	V
Supply Current	loo	RL = ∞,VCC = 30V		-	0.8	2.0	-	0.8	2.0	mA
Supply Current	Icc	RL = ∞, Vcc =	RL = ∞, VCC = 5V		0.5	1.2	-	0.5	1.2	mA
Large Signal Voltage Gain	G∨	V_{CC} = 15V, R_L = $2k\Omega$ V_O = 1V to 11V		50	100	-	25	100	-	V/mV
Output Voltage Swing	Voн	VCC = 30V	$R_L = 2k\Omega$	26	-	-	26		-	V
			R _L =10kΩ	27	28	-	27	28	-	V
	V _{O(L)}	$V_{CC} = 5V, R_{L}=10k\Omega$		-	5	20	-	5	20	mV
Common-Mode Rejection Ratio	CMRR	-		70	85	-	65	85	-	dB
Power Supply Rejection Ratio	PSRR	-		65	100	-	65	100	-	dB
Channel Separation	CS	f = 1kHz to 20l	kHz (Note1)	-	120	-	-	120	-	dB
Short Circuit to GND	Isc	-		-	40	60	-	40	60	mA
	ISOURCE	V _I (+) = 1V, V _I (-) = 0V V _{CC} = 15V, V _O (P) = 2V		20	30	-	20	30	-	mA
Output Current	Isink	V _I (+) = 1V, V _I (- VCC = 15V, V _C	10	15	-	10	15	-	mA	
ISI		Vin + = 0V, Vin VO(P) = 200m	12	100	-	12	100	-	μΑ	
Differential Input Voltage	VI(DIFF)	-	-	-	Vcc	-	-	Vcc	V	

Note:

^{1.} This parameter, although guaranteed, is not 100% tested in production.

Electrical Characteristics (Continued)

(VCC = 5.0V, VEE = GND, unless otherwise specified) The following specification apply over the range of -25°C \leq TA \leq +85°C for the LM258A; and the 0°C \leq TA \leq +70°C for the LM358A

Doromotor	Cumbal	ool Conditions			_M258	BA	L	Unit		
Parameter	Symbol	Cond	Conditions		Тур.	Max.	Min.	Тур.	Max.	Onit
Input Offset Voltage	VIO	$V_{CM} = 0V \text{ to}$ $V_{O(P)} = 1.4V$	-	-	4.0	-	-	5.0	mV	
Input Offset Voltage Drift	ΔV10/ΔΤ		-	-	7.0	15	-	7.0	20	μV/°C
Input Offset Current	ΙΙΟ		-	-	-	30	-	-	75	nA
Input Offset Current Drift	ΔΙΙΟ/ΔΤ		-	-	10	200	-	10	300	pA/°C
Input Bias Current	IBIAS	-		-	40	100	-	40	200	nA
Input Common-Mode Voltage Range	VI(R)	VCC = 30V		0	-	Vcc -2.0	0	-	Vcc -2.0	V
	Vous	/O(H) VCC = 30V	$R_L = 2k\Omega$	26	-	-	26	-	-	V
Output Voltage Swing	VO(H)		RL = 10kΩ	27	28	-	27	28	-	V
	VO(L)	VCC = 5V, R	L=10kΩ	-	5	20	-	5	20	mV
Large Signal Voltage Gain	G∨	V_{CC} = 15V, R _L =2.0kΩ $V_{O(P)}$ = 1V to 11V		25	-	-	15	-	-	V/mV
Output Current	ISOURCE	VI(+) = 1V, VI(-) = 0V VCC = 15V, VO(P) = 2V		10	30	-	10	30	-	mA
Output Current	ISINK	V _{I(+)} = 1V, V VCC = 15V,		5	9	-	5	9	-	mA
Differential Input Voltage	VI(DIFF)		-	-	-	Vcc	-	-	Vcc	V

Typical Performance Characteristics

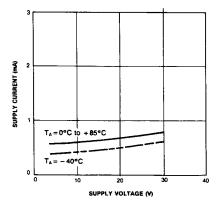


Figure 1. Supply Current vs Supply Voltage

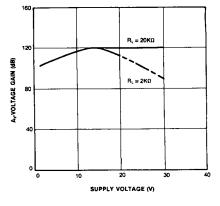


Figure 2. Voltage Gain vs Supply Voltage

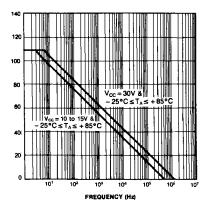


Figure 3. Open Loop Frequency Response

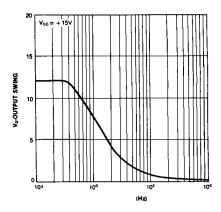


Figure 4. Large Signal Output Swing vs Frequency

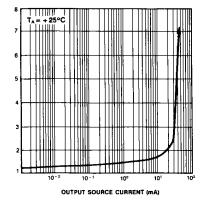


Figure 5. Output Characteristics vs Current Sourcing

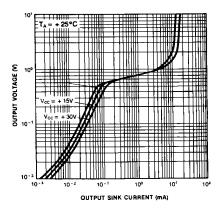


Figure 6. Output Characteristics vs Current Sinking

Typical Performance Characteristics (Continued)

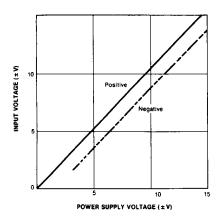


Figure 7. Input Voltage Range vs Supply Voltage

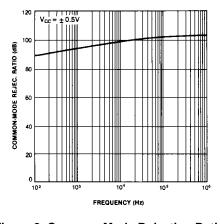


Figure 8. Common-Mode Rejection Ratio

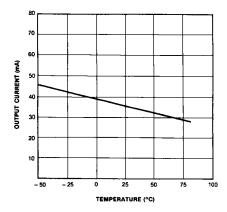


Figure 9. Output Current vs Temperature (Current Limiting)

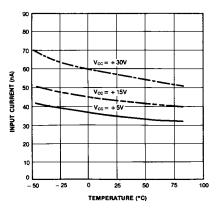


Figure 10. Input Current vs Temperature

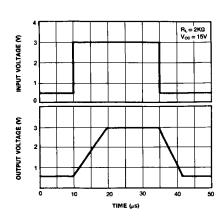


Figure 11. Voltage Follower Pulse Response

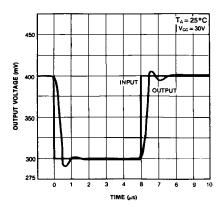
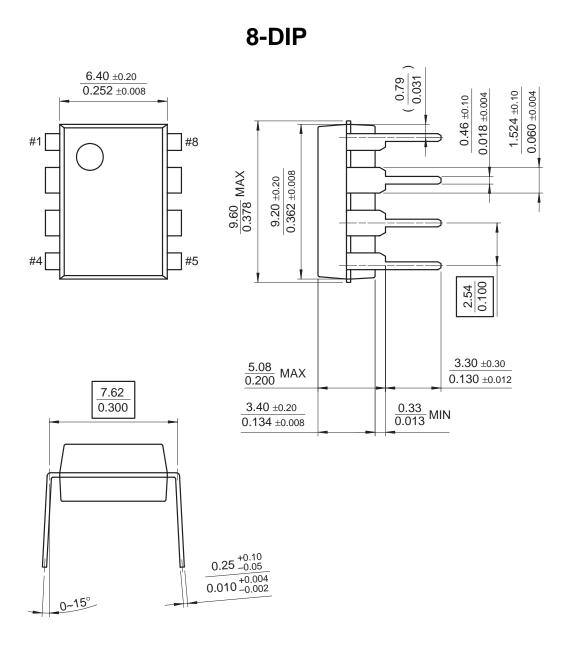


Figure 12. Voltage Follower Pulse Response (Small Signal)

Mechanical Dimensions

Package

Dimensions in millimeters

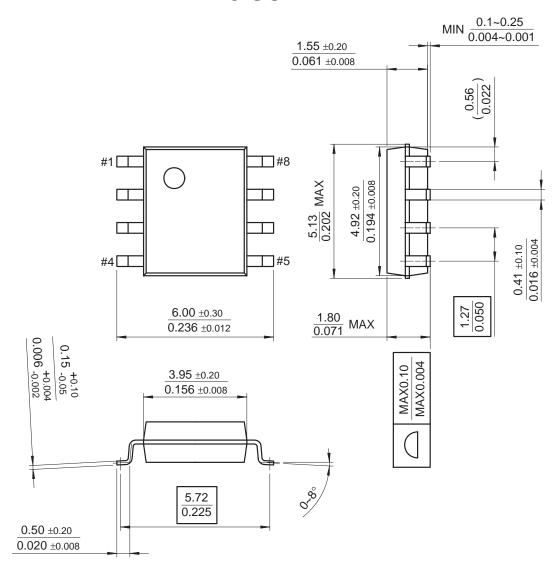


Mechanical Dimensions (Continued)

Package

Dimensions in millimeters

8-SOP



Ordering Information

Product Number	Package	Operating Temperature
LM358N	8-DIP	
LM358AN	- 0-DIF	0 ~ +70°C
LM358M	8-SOP	0~ +70 C
LM358AM	6-30F	
LM2904N	8-DIP	-40 ∼ +85°C
LM2904M	8-SOP	-40 ~ +83 C
LM258N	8-DIP	
LM258AN	- 0-DIF	-25 ~ +85°C
LM258M	8-SOP	-25 ~ +05 C
LM258AM	0-301	

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
- A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

www.fairchildsemi.com

ON Semiconductor and in are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdt/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor and see any inability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and ex

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800-282-9855 Toll Free USA/Canada
Europe, Middle East and Africa Technical Support:
Phone: 421 33 790 2910
Japan Customer Focus Center
Phone: 81-3-5817-1050

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

ON Semiconductor: